BLC9G20LS-120V

Power LDMOS transistor

AMPLEON

Rev. 3 — 5 October 2015

Product data sheet

1. Product profile

1.1 General description

120 W LDMOS power transistor with enhanced video bandwidth for base station applications at frequencies from 1805 MHz to 1995 MHz.

Table 1. Typical performance

Typical RF performance at T_{case} = 25 °C in a common source class-AB production test circuit.

Test signal	f	I_{Dq}	V _{DS}	P _{L(AV)}	G _p	η_D	ACPR _{5M}
	(MHz)	(mA)	(V)	(W)	(dB)	(%)	(dBc)
2-carrier W-CDMA	1805 to 1880	700	28	30	19.2	31	_33 <u>[1]</u>

^[1] Test signal: 3GPP test model 1; 64 DPCH; PAR = 8.4 dB at 0.01 % probability on CCDF per carrier; 5 MHz carrier spacing.

1.2 Features and benefits

- Excellent ruggedness
- High efficiency
- Low thermal resistance providing excellent thermal stability
- Decoupling leads to enable enhanced video bandwidth performance (75 MHz typical)
- Designed for broadband operation (1805 MHz to 1995 MHz)
- Lower output capacitance for improved performance in Doherty applications
- Designed for low memory effects providing excellent pre-distortability
- Internally matched for ease of use
- Integrated ESD protection
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

RF power amplifiers for base stations and multi carrier applications in the 1805 MHz to 1995 MHz frequency range

2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	drain1	5 4 0 0	4.0.5.6
2	drain2		1, 2, 5, 6
3	gate1		⊢
4	gate2	7	3, 4 —
5	video decoupling		7 aaa-016345
6	video decoupling	3 4	aaa-010343
7	source [1]		

^[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Packag	Package		
	Name	Description	Version	
BLC9G20LS-120V	-	air cavity plastic earless flanged package; 6 leads	SOT1275-3	

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{DS}	drain-source voltage			-	65	V
V_{GS}	gate-source voltage			-6	+13	V
T _{stg}	storage temperature			-65	+150	°C
T _i	junction temperature		<u>[1]</u>	-	225	°C

^[1] Continuous use at maximum temperature will affect the reliability, for details refer to the on-line MTF calculator.

5. Thermal characteristics

Table 5. Thermal characteristics

Sy	mbol	Parameter	Conditions	Тур	Unit
Rt	h(j-c)	thermal resistance from junction to case	T_{case} = 80 °C; P_{L} = 30 W	0.47	K/W

6. Characteristics

Table 6. DC characteristics

 T_i = 25 °C per section, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 1.2 \text{ mA}$	65	-	-	V
V _{GS(th)}	gate-source threshold voltage	V _{DS} = 10 V; I _D = 120 mA	1.5	1.9	3.1	V
V_{GSq}	gate-source quiescent voltage	V_{DS} = 28 V; I_{D} = 700 mA	-	2.2	-	V
I _{DSS}	drain leakage current	V _{GS} = 0 V; V _{DS} = 32 V	-	-	2.8	μΑ
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	-	25	-	Α
I _{GSS}	gate leakage current	V _{GS} = 11 V; V _{DS} = 0 V	-	-	280	nA
g _{fs}	forward transconductance	V _{DS} = 10 V; I _D = 6 A	-	4.3	-	S
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 4.2 \text{ A}$	-	0.12	-	Ω

Table 7. RF characteristics

Test signal: 2-carrier W-CDMA; 3GPP test model 1 with 64 DPCH; PAR = 8.4 dB at 0.01 % probability on the CCDF; f_1 = 1807.5 MHz; f_2 = 1812.5 MHz; f_3 = 1872.5 MHz; f_4 = 1877.5 MHz; RF performance at V_{DS} = 28 V; I_{Dq} = 700 mA; T_{case} = 25 °C; unless otherwise specified; in a water cooled class-AB test circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
G _p	power gain	P _{L(AV)} = 30 W	17.8	19.2	-	dB
η_{D}	drain efficiency	P _{L(AV)} = 30 W	29	31	-	%
RLin	input return loss	P _{L(AV)} = 30 W	-	-13	-9	dB
ACPR _{5M}	adjacent channel power ratio (5 MHz)	P _{L(AV)} = 30 W	-	-33	-28	dBc

7. Test information

7.1 Ruggedness in class-AB operation

The BLC9G20LS-120V is capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: V_{DS} = 28 V; I_{Dq} = 700 mA; P_{L} = 100 W (CW); f = 1805 MHz.

7.2 Impedance information

Table 8. Typical impedance

Measured load-pull data of the device; I_{Dq} = 700 mA; V_{DS} = 28 V; pulsed CW (t_p = 100 μ s; δ = 10 %).

f	Z _S [1]	Z _L [1]	P _L [2]	η _D [2]	G _p [2]	
(MHz)	(Ω)	(Ω)	(W)	(%)	(dB)	
Maximum	Maximum power load					
1805	1.6 – j5.4	1.6 – j4.2	169.6	59.4	16.3	
1840	2.4 – j6.0	1.5 – j4.0	170.3	59.0	16.2	
1880	2.7 – j6.2	1.6 – j4.1	168.0	59.6	16.5	
1930	3.7 – j7.6	1.4 - j3.9	167.9	58.3	16.3	
1960	3.8 - j8.0	1.5 – j4.2	166.8	57.3	16.5	
1990	5.0 - j7.9	1.4 – j4.1	162.1	57.2	16.6	
Maximum	drain efficiency lo	ad	,	,	1	
1805	1.6 – j5.4	2.9 - j2.6	117.0	70.1	18.6	
1840	2.4 – j6.0	2.8 - j2.6	116.5	69.9	18.7	
1880	2.7 – j6.2	2.5 – j2.4	110.7	69.8	19.0	
1930	3.7 – j7.6	2.5 – j2.7	115.4	68.2	19.0	
1960	3.8 - j8.0	2.0 - j2.6	113.6	67.5	19.0	
1990	5.0 - j7.9	2.0 - j2.7	113.6	66.7	19.1	

- [1] Z_S and Z_L defined in Figure 1.
- [2] at 3 dB gain compression.

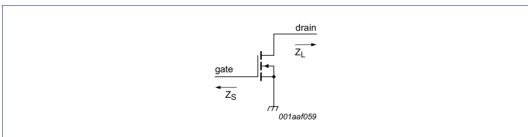
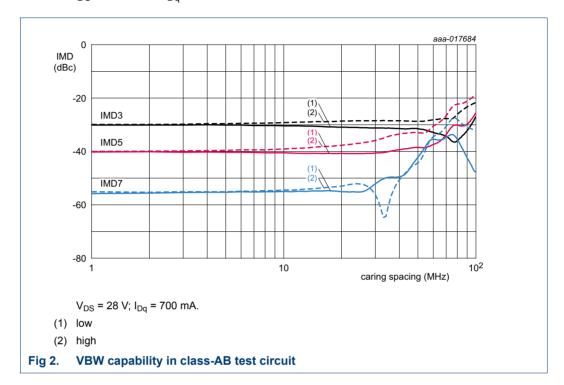


Fig 1. Definition of transistor impedance

7.3 VBW in a class-AB operation

The BLC9G20LS-120V shows 75 MHz (typical) video bandwidth (IMD third-order intermodulation inflection point) in a class-AB test circuit in the 1805 MHz to 1880 MHz band at V_{DS} = 28 V and I_{Dq} = 700 mA.



7.4 Test circuit

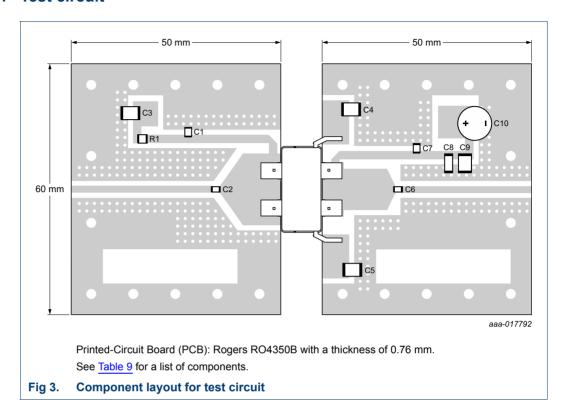


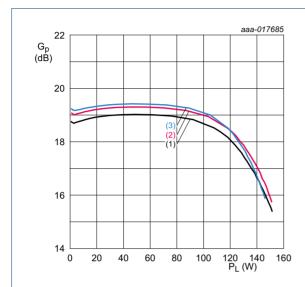
Table 9. List of componentsSee Figure 3 for component layout.

Component	Description	Value	Remarks
C1, C7	multilayer ceramic chip capacitor	43 pF [1]	ATC 600F
C2	multilayer ceramic chip capacitor	3.9 pF [2]	ATC 100A
C3, C4, C5, C9	multilayer ceramic chip capacitor	1.0 μF, 50 V	Murata
C6	multilayer ceramic chip capacitor	1.5 pF [1]	ATC 600F
C8	multilayer ceramic chip capacitor	220 nF, 50 V	Murata
C10	electrolytic capacitor	> 470 μF, 50 V	
R1	resistor	2.2 Ω, 1 % tolerance	SMD 1206

- [1] American Technical Ceramics type 600F or capacitor of same quality.
- [2] American Technical Ceramics type 100A or capacitor of same quality.
- [3] Murata or capacitor of same quality.

7.5 Graphical data

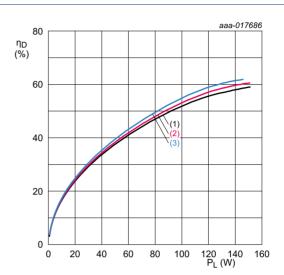
7.5.1 Pulsed CW



 V_{DS} = 28 V; I_{Dq} = 700 mA; t_p = 100 μ s; δ = 10 %.

- (1) f = 1807.5 MHz
- (2) f = 1840.0 MHz
- (3) f = 1872.5 MHz

Fig 4. Power gain as a function of output power; typical values

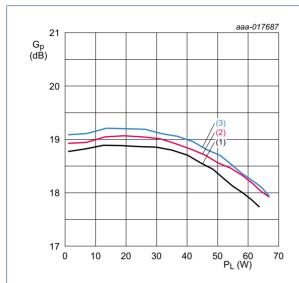


 V_{DS} = 28 V; I_{Dq} = 700 mA; t_p = 100 $\mu s; \, \delta$ = 10 %.

- (1) f = 1807.5 MHz
- (2) f = 1840.0 MHz
- (3) f = 1872.5 MHz

Fig 5. Drain efficiency as a function of output power; typical values

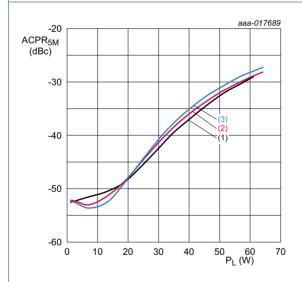
7.5.2 1-Carrier W-CDMA



 $V_{DS} = 28 \text{ V}; I_{Dq} = 700 \text{ mA}.$

- (1) f = 1807.5 MHz
- (2) f = 1840.0 MHz
- (3) f = 1872.5 MHz

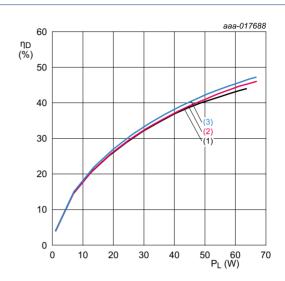
Fig 6. Power gain as a function of output power; typical values



 $V_{DS} = 28 \text{ V}; I_{Dq} = 700 \text{ mA}.$

- (1) f = 1807.5 MHz
- (2) f = 1840.0 MHz
- (3) f = 1872.5 MHz

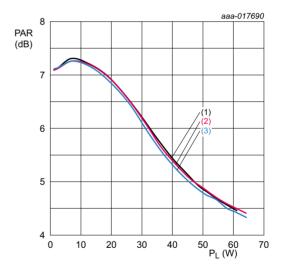
Fig 8. Adjacent channel power ratio (5 MHz) as a function of output power; typical values



 $V_{DS} = 28 \text{ V}; I_{Dq} = 700 \text{ mA}.$

- (1) f = 1807.5 MHz
- (2) f = 1840.0 MHz
- (3) f = 1872.5 MHz

Fig 7. Drain efficiency as a function of output power; typical values

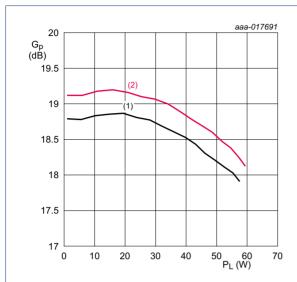


 $V_{DS} = 28 \text{ V}; I_{Dq} = 700 \text{ mA}.$

- (1) f = 1807.5 MHz
- (2) f = 1840.0 MHz
- (3) f = 1872.5 MHz

Fig 9. Peak-to-average ratio as a function of output power; typical values

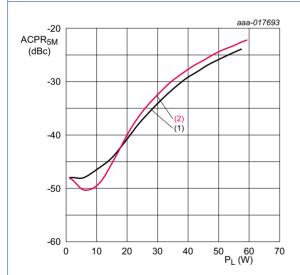
7.5.3 2-Carrier W-CDMA



 V_{DS} = 28 V; I_{Dq} = 700 mA; 5 MHz carrier spacing.

- (1) f = 1810 MHz
- (2) f = 1875 MHz

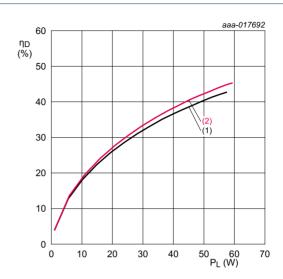
Fig 10. Power gain as a function of output power; typical values



V_{DS} = 28 V; I_{Dq} = 700 mA; 5 MHz carrier spacing.

- (1) f = 1810 MHz
- (2) f = 1875 MHz

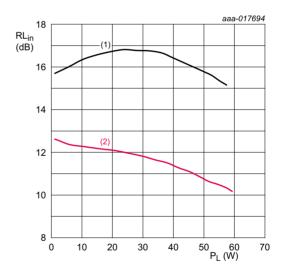
Fig 12. Adjacent channel power ratio (5 MHz) as a function of output power; typical values



 V_{DS} = 28 V; I_{Dq} = 700 mA; 5 MHz carrier spacing.

- (1) f = 1810 MHz
- (2) f = 1875 MHz

Fig 11. Drain efficiency as a function of output power; typical values



 V_{DS} = 28 V; I_{Dq} = 700 mA; 5 MHz carrier spacing.

- (1) f = 1810 MHz
- (2) f = 1875 MHz

Fig 13. Input return loss as a function of output power; typical values

8. Package outline

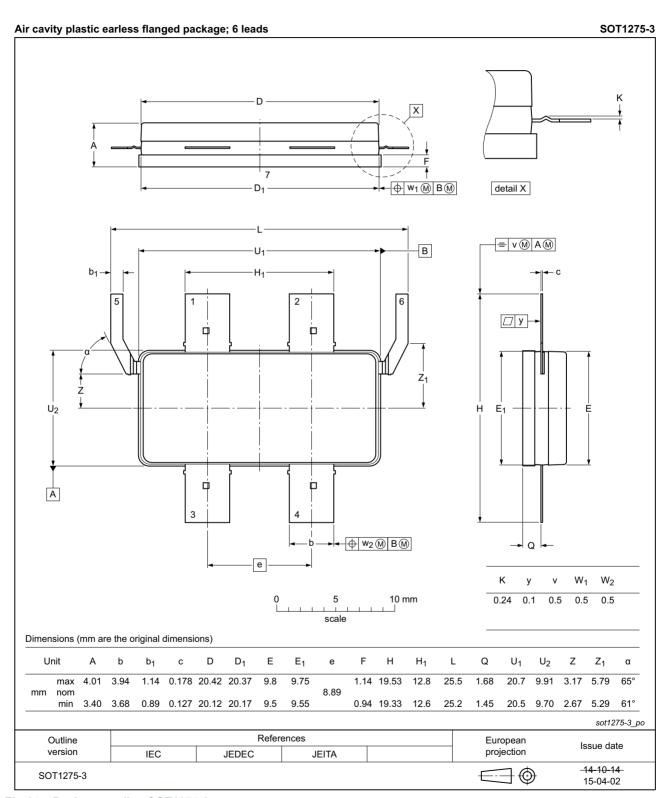


Fig 14. Package outline SOT1275-3

9. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

10. Abbreviations

Table 10. Abbreviations

Acronym	Description	
3GPP	3rd Generation Partnership Project	
CCDF	Complementary Cumulative Distribution Function	
CW	Continuous Wave	
DPCH	Dedicated Physical CHannel	
ESD	ElectroStatic Discharge	
LDMOS	Laterally Diffused Metal Oxide Semiconductor	
MTF	Median Time to Failure	
PAR	Peak-to-Average Ratio	
SMD	Surface Mounted Device	
VBW	Videoband Width	
VSWR	Voltage Standing Wave Ratio	
W-CDMA	Wideband Code Division Multiple Access	

11. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
BLC9G20LS-120V v.3	20151005	Product data sheet	-	BLC9G20LS-120V v.2		
Modifications:	Section 1.1 on	• Section 1.1 on page 1: changed "improved video bandwidth" to "enhanced video bandwidth"				
	Section 1.2 on	page 1: changed "improved	d video bandwidth" to	"enhanced video bandwidth"		
	Table 6 on page	$ge 3$: the typical value for V_G	s _{Sq} has been updated			
	Table 7 on page	ge 3: several values have be	en updated			
	Table 8 on page	ge 4: the title of this table ha	s been changed			
	Table 8 on page	ge 4: some values have bee	n changed			
BLC9G20LS-120V v.2	20150901	Objective data sheet	-	BLC9G20LS-120V v.1		
Modifications:	The format of this document has been redesigned to comply with the new identity guidelines of Ampleon					
	Legal texts have been adapted to the new company name where appropriate					
BLC9G20LS-120V v.1	20150703	Objective data sheet	-	-		

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12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions"
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Power LDMOS transistor

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BLC9G20LS-120V

Power LDMOS transistor

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